

FIG.1A
(PRIOR ART)

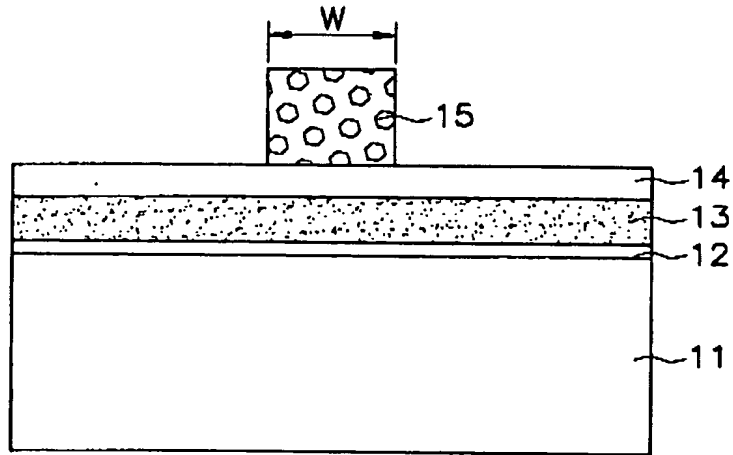


FIG.1B
(PRIOR ART)

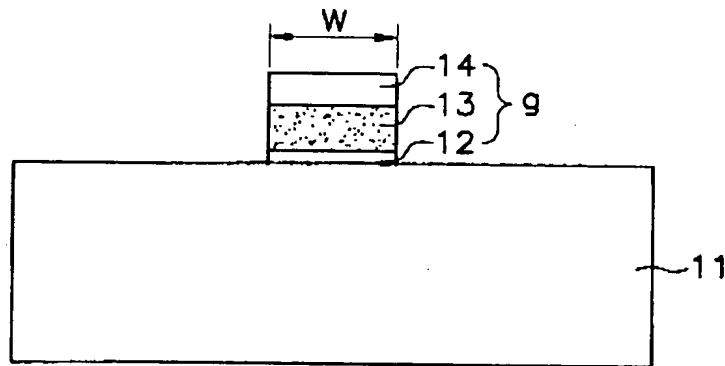


FIG. 2B

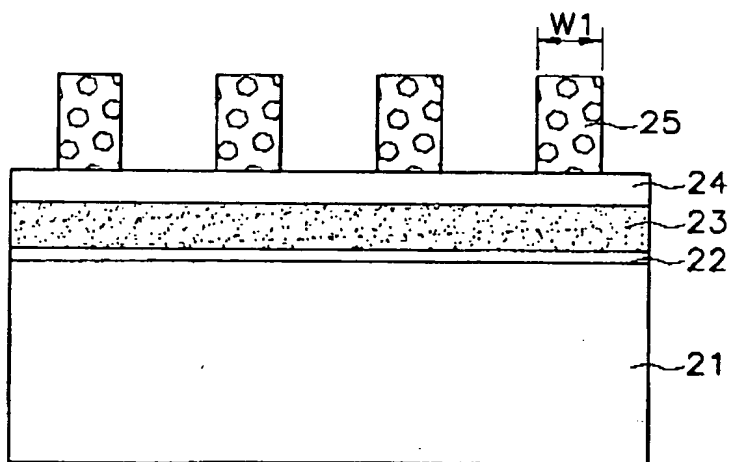


FIG.2C

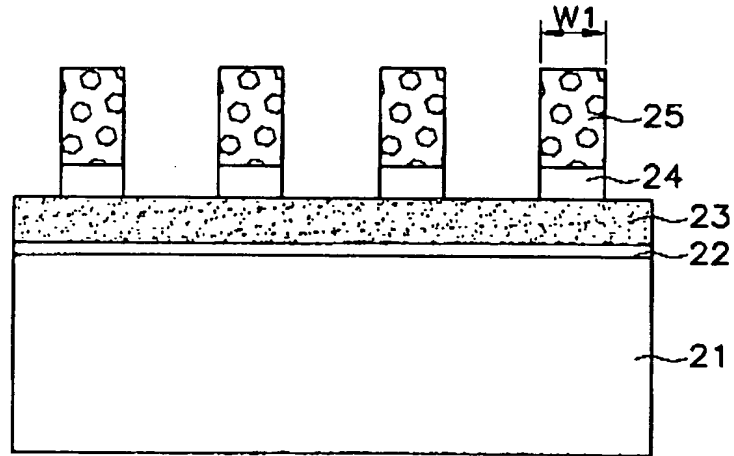
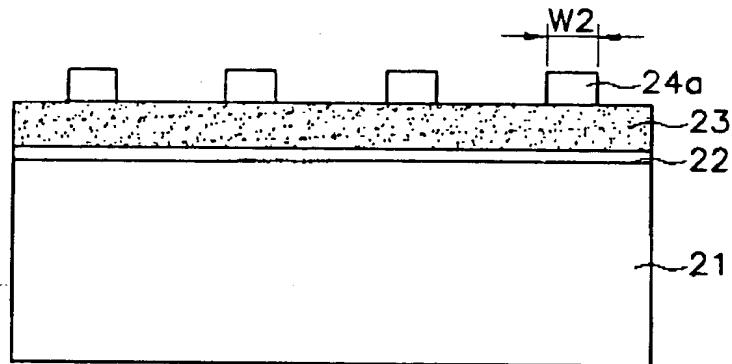


FIG.2D



A cross-sectional view of a semiconductor device. A substrate 21 is shown at the bottom. On top of the substrate, there are four stacked layers. The bottom layer is labeled 22, the second layer is 23, the third layer is 24, and the top layer is 24a. A bracket labeled G groups layers 22, 23, and 24. The layers 22 and 23 contain small dots, while layers 24 and 24a are solid.